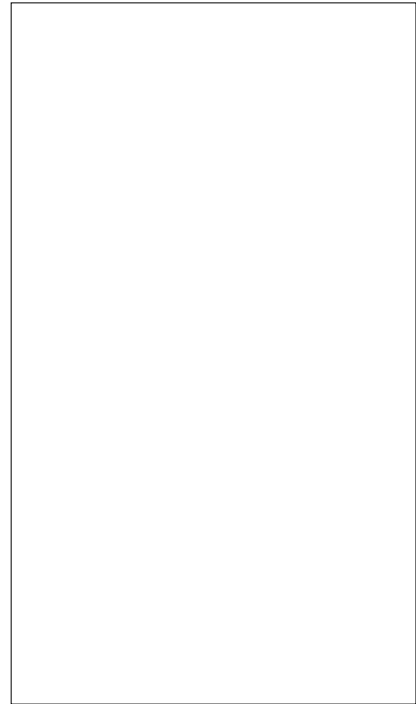




JCT655T 55A SCR

Rev.A.1.0

With high ability to withstand the shock loading of large current, JCT655T SCR provides high dV/dt rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Complying with UL standards (File ref: E252906). Package TG-C is RoHS compliant.



Average gate power dissipation ($T_j=125$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	20	W
Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.7)	V_{pp}	0.7	kV

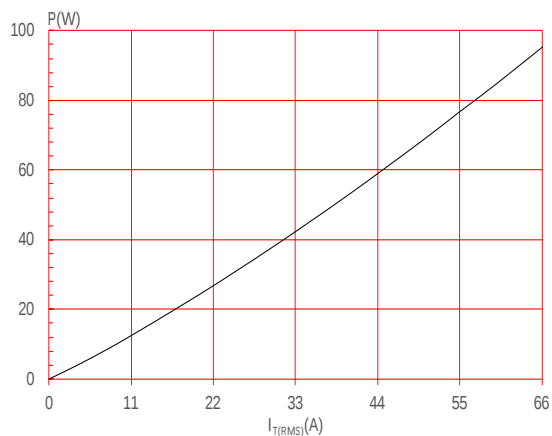
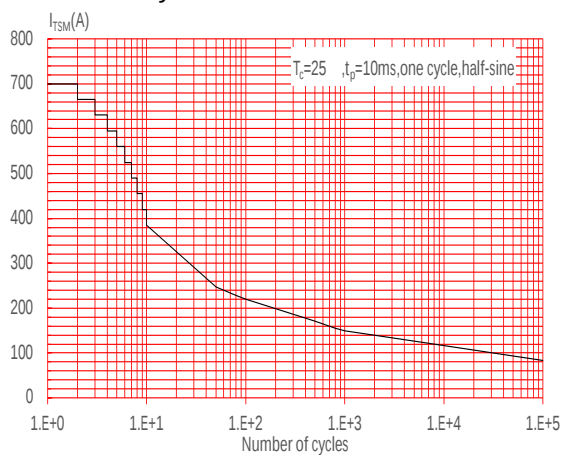
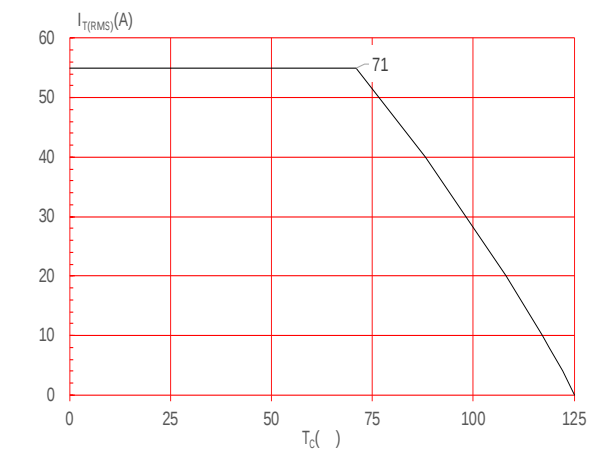
(T_j=25 unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	$V_D=12V$ $R_L=33\Omega$	10	-	50	mA
V_{GT}		-	-	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125$ $R_L=3.3k\Omega$	0.2	-	-	V
I_L	$I_G=1.2I_{GT}$	-	-	120	mA
I_H	$I_T=500mA$	-	-	100	mA
dV/dt	$V_D=400V$ Gate Open $T_j=125$	2000	-	-	V/ μs
t_{on}	$I_G=50mA$ $I_A=500mA$ $I_R=50mA$ $T_j=25$	-	4	-	μs
t_{off}		-	130	-	

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=80A$ $t_p=380\mu s$	$T_j=25$	1.5	V
V_{TO}	Threshold voltage	$T_j=125$	0.76	V
R_D	Dynamic resistance	$T_j=125$	8.5	m Ω
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25$	8	μA
I_{RRM}		$T_j=125$	4	mA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case(DC)	0.7	/W
$R_{th(j-a)}$	junction to ambient (DC)	45	/W

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FIG.1: Maximum power dissipation versus RMS on-state current**FIG.3:** Surge peak on-state current versus number of cycles**FIG.2:** RMS on-state current versus case temperature**FIG.4:** On-state characteristics

JCT655T

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